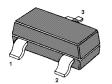
## SILICON EPITAXIAL PLANAR SWITCHING DIODE

## **Application**

• Ultra high speed switching





Marking Code: **A4** SOT-23 Plastic Package

Absolute Maximum Ratings ( $T_a = 25$  °C)

Parameter	Symbol	Value	Unit
Maximum Peak Reverse Voltage	$V_{RM}$	80	V
Reverse Voltage	V <sub>R</sub>	80	V
Average Forward Current	Io	100	mA
Maximum Peak Forward Current	I <sub>FM</sub>	300	mA
Surge Current (t = 1 µs)	I <sub>FSM</sub>	4	А
Power Dissipation	P <sub>tot</sub>	200	mW
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature Range	T <sub>s</sub>	- 55 to + 150	°C

## Characteristics at T<sub>a</sub> = 25 °C

Parameter	Symbol	Max.	Unit
Forward Voltage at I <sub>F</sub> = 100 mA	V <sub>F</sub>	1.2	V
Reverse Current at V <sub>R</sub> = 70 V	I <sub>R</sub>	0.1	μΑ
Total Capacitance at $V_R = 6 \text{ V}$ , $f = 1 \text{ MHz}$	Ст	3.5	pF
Reverse Recovery Time at $V_R = 6 \text{ V}$ , $I_F = 5 \text{ mA}$ , $R_L = 50 \Omega$	t <sub>rr</sub>	4	ns



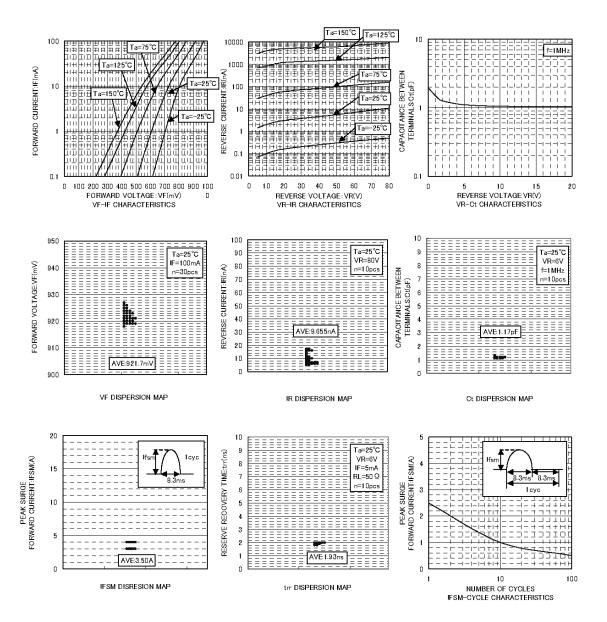






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Dated: 10/10/2008